

High Cathode Sensitivity with Low Noise Photocathode

FEATURES

- Spectral Response 185 to 680 nm
- Cathode Sensitivity
 - Luminous 60 μ A/lm
 - Radiant at 400nm 60 mA/W
- Anode Sensitivity (at 1000V)
 - Luminous 400 A/lm
 - Radiant at 400nm 4.0×10^5 A/W
- Low Dark Current 0.1 nA
- Low Dark Counts (R1527P) 10 cps

Hamamatsu R1527 features high cathode sensitivity, high current amplification, and low dark current.

Variant tube (R1527P) specially selected for photon counting application is also available.

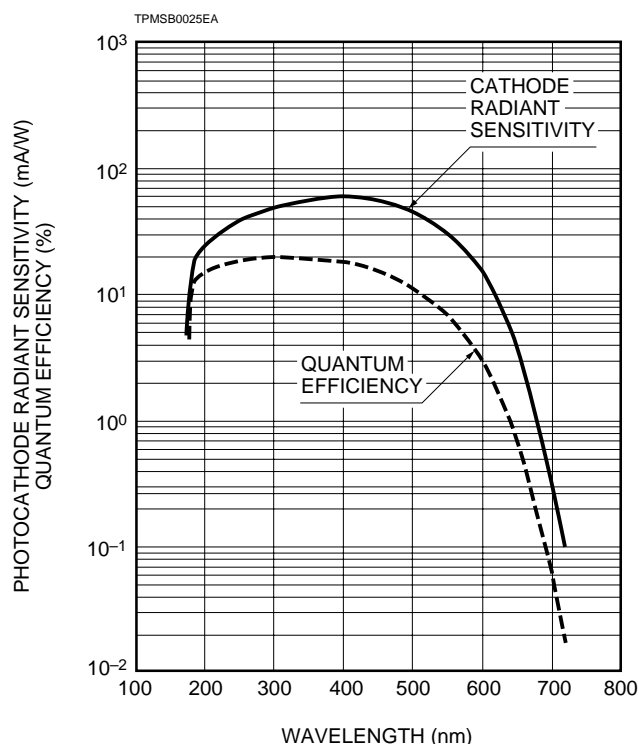
The R1527 is useful for fluorescence, chemiluminescence, Raman spectroscopy and low light level detection.



GENERAL

| Parameter | Description/Value | Unit |
|------------------------------------|---------------------------------|------|
| Spectral Response | 185 to 680 | nm |
| Wavelength of Maximum Response | 400 | nm |
| Photocathode | | |
| Material | Low noise bialkali | — |
| Minimum Effective Area | 8 × 24 | mm |
| Window Material | UV glass | — |
| Dynode | | |
| Secondary Emitting Surface | Low noise bialkali | — |
| Structure | Circular-cage | — |
| Number of Stages | 9 | — |
| Direct Interelectrode Capacitances | | |
| Anode to Last Dynode | 4 | pF |
| Anode to All Other Electrodes | 6 | pF |
| Base | 11-pin base JEDEC No. B11-88 | — |
| Weight | 45 | g |
| Suitable Socket | E678-11A (option) | — |
| Suitable Socket Assembly | E717-21 (option) | — |

Figure 1: Typical Spectral Response



PHOTOMULTIPLIER TUBES R1527, R1527P(For Photon Counting)

MAXIMUM RATINGS (Absolute Maximum Values)

| Parameter | Value | Unit |
|-------------------------------|------------|------|
| Supply Voltage | | |
| Between Anode and Cathode | 1250 | Vdc |
| Between Anode and Last Dynode | 250 | Vdc |
| Average Anode Current | 0.1 | mA |
| Ambient Temperature | -80 to +50 | °C |

CHARACTERISTICS (at 25°C)

| Parameter | R1527 for General Purpose | | | R1527P for Photon Counting | | | Unit |
|--|------------------------------|-------------------------|------|-------------------------------|-------------------------|------|---------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. | |
| Cathode Sensitivity | | | | | | | |
| Quantum Efficiency at 300nm (Peak) | — | 19 | — | — | 19 | — | % |
| Luminous ^B | 40 | 60 | — | 40 | 60 | — | μA/lm |
| Radiant at 400nm (Peak) | — | 60 | — | — | 60 | — | mA/W |
| Blue ^C | — | 6.4 | — | — | 6.4 | — | μA/lm-b |
| Anode Sensitivity | | | | | | | |
| Luminous ^D | 200 | 400 | — | 200 | 400 | — | A/lm |
| Radiant at 400nm | — | 4.0 × 10 ⁵ | — | — | 4.0 × 10 ⁵ | — | A/W |
| Gain ^E | — | 6.7 × 10 ⁶ | — | — | 6.7 × 10 ⁶ | — | |
| Anode Dark Current ^E | | | | | | | |
| After 30minute Storage in the darkness | — | 0.1 | 2.0 | — | 0.1 | 0.5 | nA |
| Anode Dark Counts ^F | — | — | — | — | 10 | 50 | cps |
| ENI(Equivalent Noise Input) ^G | — | 3.7 × 10 ⁻¹⁷ | — | — | 3.7 × 10 ⁻¹⁷ | — | W |
| Time Response ^D | | | | | | | |
| Anode Pulse Rise Time ^H | — | 2.2 | — | — | 2.2 | — | ns |
| Electron Transit Time ^J | — | 22 | — | — | 22 | — | ns |
| Transit Time Spread (TTS) ^K | — | 1.2 | — | — | 1.2 | — | ns |
| Anode Current Stability ^L | | | | | | | |
| Current Hysteresis | — | 0.1 | — | — | 0.1 | — | % |
| Voltage Hysteresis | — | 1.0 | — | — | 1.0 | — | % |

NOTES

- A: Averaged over any interval of 30 seconds maximum.
 B: The light source is a tungsten filament lamp operated at a distribution temperature of 2856K. Supply voltage is 150 volts between the cathode and all other electrodes connected together as anode.
 C: The value is cathode output current when a blue filter(Corning CS-5-58 polished to 1/2 stock thickness) is interposed between the light source and the tube under the same condition as Note B.
 D: Measured with the same light source as Note B and with the anode-to-cathode supply voltage and voltage distribution ratio shown in Table 1 below.
 E: Measured with the same supply voltage and voltage distribution ratio as Note D after removal of light.
 F: Measured at the voltage producing the gain of 1 × 10⁶.
 G: ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

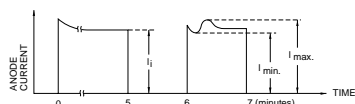
$$ENI = \frac{\sqrt{2q \cdot I_{db} \cdot G \cdot f}}{S}$$

- where q = Electronic charge (1.60 × 10⁻¹⁹ coulomb).
 I_{db} = Anode dark current(after 30 minute storage) in amperes.
 G = Gain.
 f = Bandwidth of the system in hertz. 1 hertz is used.
 S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.

- H: The rise time is the time for the output pulse to rise from 10% to 90% of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
 J: The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.

- K: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.
 L: Hysteresis is temporary instability in anode current after light and voltage are applied.

$$\text{Hysteresis} = \frac{I_{\max} - I_{\min}}{I_i} \times 100(\%)$$



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(1)Current Hysteresis

The tube is operated at 750 volts with an anode current of 1 micro-ampere for 5 minutes. The light is then removed from the tube for a minute. The tube is then re-illuminated by the previous light level for a minute to measure the variation.

(2)Voltage Hysteresis

The tube is operated at 300 volts with an anode current of 0.1 micro-ampere for 5 minutes. The light is then removed from the tube and the supply voltage is quickly increased to 800 volts. After a minute, the supply voltage is then reduced to the previous value and the tube is re-illuminated for a minute to measure the variation.

Table 1:Voltage Distribution Ratio

| Electrode | K | Dy1 | Dy2 | Dy3 | Dy4 | Dy5 | Dy6 | Dy7 | Dy8 | Dy9 | P |
|--------------------|---|-----|-----|-----|-----|-----|-----|-----|-----|-----|---|
| Distribution Ratio | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 |

Supply Voltage : 1000Vdc

K : Cathode, Dy : Dynode, P : Anode

Figure 2: Typical Gain and Anode Dark Current

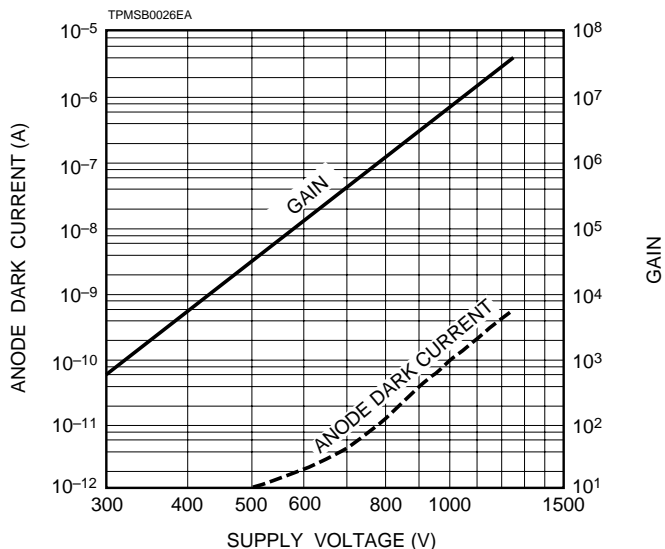


Figure 3: Typical Time Response

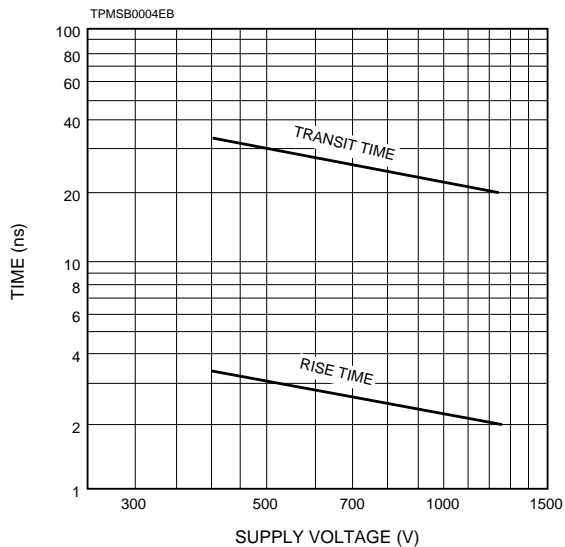


Figure 4: Typical ENI vs. Wavelength

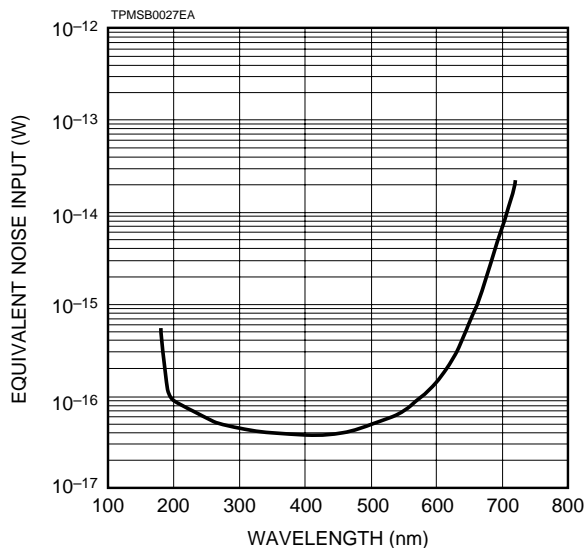
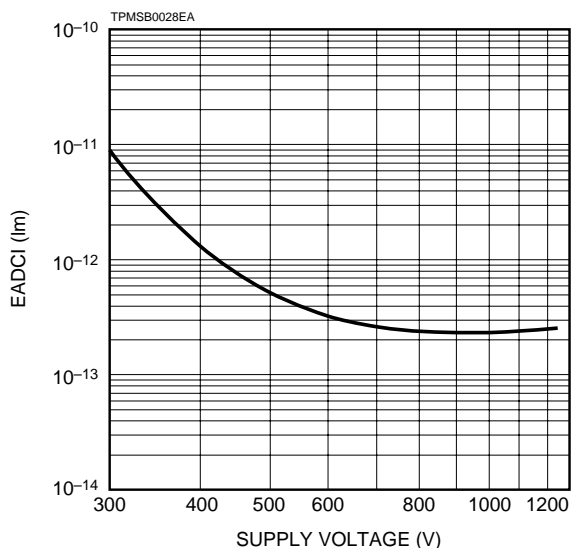


Figure 5: Typical EADCI (Equivalent Anode Dark Current Input) vs. Supply Voltage



Data shown here, which is given from a relation among supply voltage, anode sensitivity and dark current, serves as a good reference in order to determine the most suitable supply voltage or its range.

Figure 6: Typical Single Photon Height Distribution for R1527P

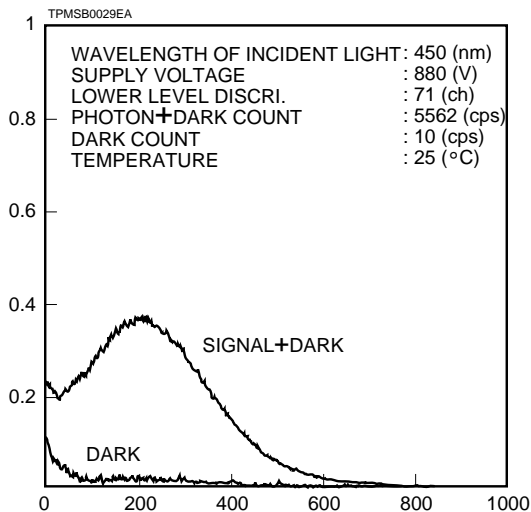
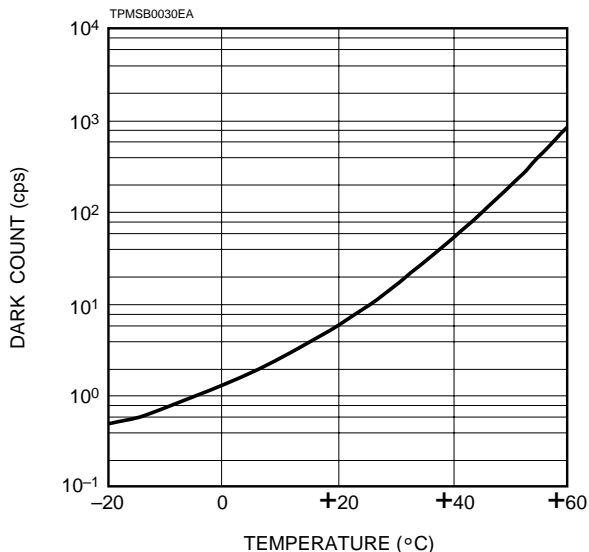
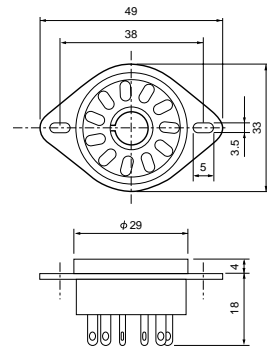
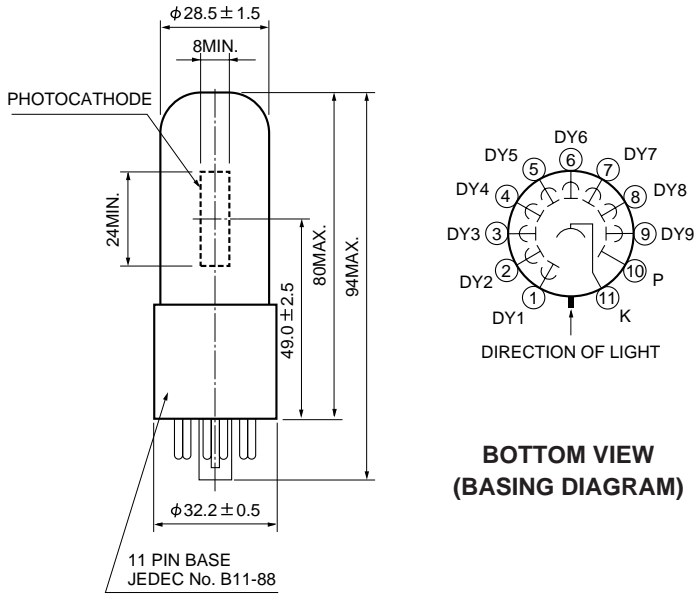


Figure 7: Typical Temperature Characteristics of Dark Count for R1527P



PHOTOMULTIPLIER TUBES R1527, R1527P(For Photon Counting)

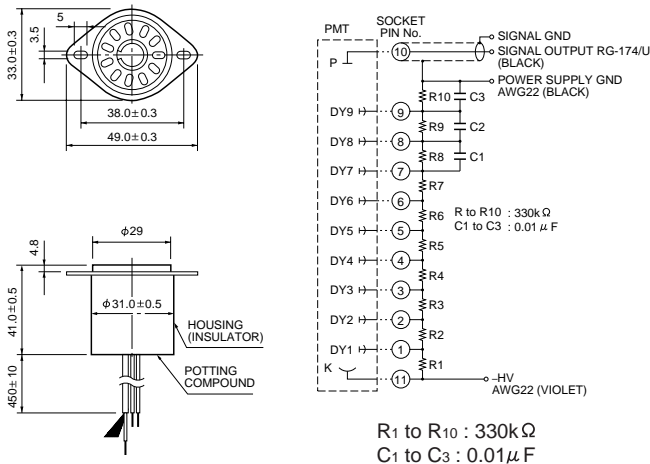
Figure 8: Dimensional Outline and Basing Diagram(Unit: mm) Figure 10: Socket E678-11A (Optional)



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TPMSA0001EA

Figure 9: D Type Socket Assembly E717-21 (Optional)



TACCA0002ED

※ Hamamatsu also provides C4900 series compact high voltage power supplies and C6270 series DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.

Warning—Personal Safety Hazards
Electrical Shock—Operating voltages applied to this device present a shock hazard.

HAMAMATSU

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